# Fast Switching SPDT RF Switch

Absorptive RF Switch with internal driver

# The Big Deal

- High Isolation, 56 dB typ.
- High Input IP3, +46.5 dBm typ.
- Low insertion loss, 0.6 dB typ.
- Fast Rise/Fall time, 3.3 ns / 4.6 ns typ.
- Tiny Size, 3.25 x 3.25 x 0.9 mm



M3SWA-2-50DRB+

CASE STYLE: DL805

# **Product Overview**

Mini-Circuits' M3SWA-2-50DRB+ is a MMIC SPDT absorptive switch with an internal driver designed for wideband operation from DC to 4.5 GHz supporting many applications requiring fast switching across a wide frequency range. This model provides excellent isolation, fast switching speed and high linearity in a tiny 3.25 x 3.25mm 8-Lead MCLP package.

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Feature	Advantages		
Wideband, DC to 4.5 GHz	One model can be used in many applications, saving component count. Also ideal for wideband applications such as military and instrumentation.		
Absorptive switch	In the OFF condition, RF output ports which are not switched ON are terminated into $50\Omega$ . This enables proper impedance termination of the circuitry following the RF output ports, preventing any unintended action such as oscillation.		
High Isolation: • 62 dB at 1000 MHz • 35 dB at 4500 MHz	High isolation significantly reduces leakage of power into OFF ports.		
High linearity: Input power at P1dB, 25.4 dBm typ. Input IP3, +46.5 dBm typ.	High linearity minimizes unwanted intermodulation products which are difficult or impossible to filter in multi-carrier environments such as CATV, or in the presence of strong interfering signal from adjacent circuitry or received by antenna.		
Form-fit compatible with M3SWA-250DR+	Fits into existing PCB footprint designed for M3SWA-2-50DR+ with minor electrical differences.		
Tiny size, 3.25 x 3.25 mm MCLP package	Tiny footprint saves space in dense layouts while providing low inductance, repeat- able transitions, and excellent thermal contact to the PCB.		

# **Key Features**

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## **Product Features**

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- Low insertion loss, 0.6 dB typ.
- Fast Rise/Fall time, 3.3 ns / 4.6 ns typ.
- High Input IP3, +46.5 dBm typ.
- Replaces M3SWA-2-50DR+

## **Typical Applications**

- Defense
- Communication Infrastructure
- Test and Measurements

# M3SWA-2-50DRB+

50Ω

DC - 4500 MHz

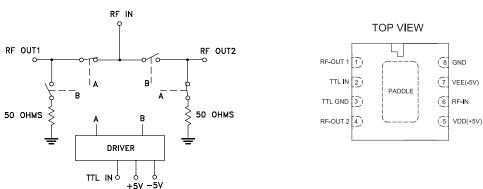


CASE STYLE: DL805

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

#### **General Description**

M3SWA-2-50DRB+ is a high isolation fast switching absorptive GaAs PHEMT SPDT switch with an internal driver. It operates at +5V & -5V power supplies and has a single TLL compatible control port. It has been designed for wideband operation and packaged in a tiny 3.25mm x 3.25mm, 8-lead package.



#### Simplified Schematic and Pad Description

Function	Pad Number	Description	
RF-IN	6	RF Common/ SUM port	
RF-OUT1	1	RF Output port #1	
RF-OUT2	4	RF Output port #2	
TTL IN	2	TTL Compatible Control Voltage Input	
TTL GND	3	TTL Ground	
V <sub>DD</sub> (+5V)	5	Positive Supply Voltage V <sub>DD</sub>	
V <sub>EE</sub> (-5V)	7	Negative Supply Voltage V <sub>EE</sub>	
GND	8, paddle	Ground	

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#### **SPDT RF Switch**

# M3SWA-2-50DRB+

# RF Electrical Specifications<sup>1</sup>, $T_{AMB}$ =25°C, 50 $\Omega$ , $V_{DD}$ = +5V, $V_{EE}$ = -5V

Parameter	Condition (MHz)	Min.	Тур.	Max.	Units
Frequency range <sup>3</sup>		DC		4500	MHz
	10 - 100	_	0.5	1.0	
	100 - 1000	_	0.6	1.2	
Insertion loss	1000 - 2000	_	0.6	1.4	dB
	2000 - 4000	_	0.7	2.0	
	4000 - 4500	_	1.4	2.5	
	10 - 100		78		
	100 - 1000		59		
Isolation between Output Port 1 & 2	1000 - 2000		49		dB
	2000 - 4000		39		
	4000 - 4500		32		
	10 - 100	65	97	_	
	100 - 1000	53	75	_	
Isolation between Common Port & Output Ports	1000 - 2000	45	56	_	dB
	2000 - 4000	30	43	_	
	4000 - 4500	30	36	_	
	10 - 100		29		
	100 - 1000		30		
Input Return loss	1000 - 2000		27		dB
	2000 - 4000		23		
	4000 - 4500		22		
	10 - 100		29		
	100 - 1000		28		
Output Return loss (Both ON STATE & OFF STATE)	1000 - 2000		22		dB
(BOUT ON STATE & OFF STATE)	2000 - 4000		19		
	4000 - 4500		14		
	10 - 100		19.2		
	100 - 1000		24.5		
Input Power at P1dB <sup>2</sup>	1000 - 2000		25.4		dBm
	2000 - 4000		25.0		
	4000 - 4500		23.8		
	10 - 100		39.7		
	100 - 1000		44.7		
Input IP3	1000 - 2000		46.5		dBm
(Pout=0 dBm/Tone)	2000 - 4000		44.0		
	4000 - 4500		40.1		
Thermal Resistance - Junction-to-ground lead at 85°C stage temperature			34.2		°C/W

#### **DC Electrical Specifications**

Parameter	Min.	Тур.	Max.	Units
Positive Supply Voltage, $V_{DD}$	4.75	5	5.25	V
Negative Supply voltage, $V_{EE}$	-5.25	-5	-4.75	V
Positive Supply Current, I <sub>DD</sub>	—	5	9	mA
Negative Supply Current, IEE	-9	-3	_	mA
Control Voltage Low	—	0	0.8	V
Control Voltage High	2.1	2.3	5	V
Control Current Low	_	0	0.2	mA
Control Current High	—	0.4	5	mA

Notes:

1. Tested on Mini-Circuits' test board TB-M3SWA250DRB+ (See Fig.1)

2. Input Power at P1dB compression drops to 13 dB at 10 MHz. 3. All RF-ports must be DC blocked or held at 0V DC.

#### **Switching Specifications**

Parameter	Condition	Min.	Тур.	Max.	Units
ON Time, 50% control to 90% RF			14.4		ns
OFF Time, 50% control to 10% RF	RF Pin= 0 dBm RF Freg.= 500 MHz		11.3		ns
Video Leakage	Control Freq.= 500 KHz		42.5		mV
Rise Time, 10% RF to 90% RF	Control High= 2.3V Control Low= 0V		3.3		ns
Fall Time, 90% RF to 10% RF			4.6		ns

# 

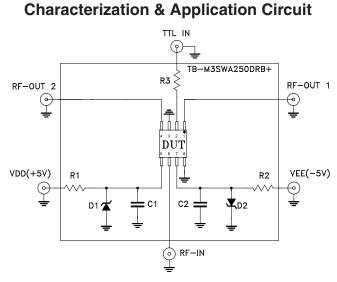
#### Absolute Maximum Ratings<sup>4</sup>

Parameter	Ratings
Operating temperature	-55°C to +100°C
Storage temperature	-55°C to +100°C
RF Input power	+24 dBm
Junction Temperature	134°C
Total Power Dissipation	0.4W
DC Voltage, Pin 5	+6V
DC Voltage, Pin 7	-6V

 Permanent damage may occur if any of these limits are exceeded. Electrical Maximum ratings are not intended for continuous normal operation.

#### **Truth Table**

State of Control Voltage	RF-IN to RF-OUT1	RF-IN to RF-OUT 2
LOW	ON	OFF
HIGH	OFF	ON



Component	Size	Value	P/N	Manufacturer
DUT	3.25x3.25	N/A	M3SWA-2-50DRB+	MCL
D1, D2	SOD-123	Vz = 5.6V	MMSZ4690T1G	ON Semiconductor
R1, R2	0603	11.5Ω	RK73H1JTTD11R5F	KOA
R3	0603	100Ω	RK73H1JTTD1000F	KOA
C1, C2	0603	10pF	06031A100GAT2A	AVX

Note: D1&D2 are optional.

#### Figure 1. Characterization & Application Circuit

Note: (DUT soldered on Mini-Circuits Characterization & Application Test Board TB-M3SWA250DRB+). Insertion Loss, Amplitude Unbalance, Isolation, Return Loss, Input Power at 1dB Compression (P1dB) & Input IP3 tested using E5071C microwave network analyzer. Condition:

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1. Insertion Loss, Amplitude Unbalance, Isolation & Return Loss: Pin = 0dBm

2. Input IP3(IIP3):Two tones, spaced 1 MHz apart, 0dBm/tone output.

## **Product Marking**



Marking may contain other features or characters for internal lot control



## **Additional Detailed Technical Information**

additional information is available on our dash board.

Performance Data	Data Table	
Performance Data	Swept Graphs	
Case Style	DL805 Plastic package, exposed paddle , lead finish=Matte-Tin	
Tape & Reel	F58	
Standard quantities available on reel	7" reels with 1000 devices 13" reels with 2000, 4000 devices	
Suggested Layout for PCB Design	PL-120	
Evaluation Board	TB-M3SWA250DRB+	
Environmental Ratings	ENV16	

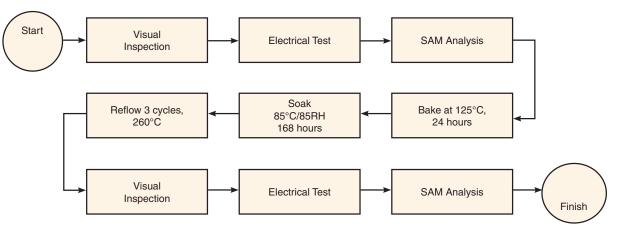
## **ESD** Rating

Human Body Model (HBM): Class 0 (Pass 100V) in accordance with ESD STM5.1-2001

## **MSL** Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

## **MSL Test Flow Chart**



#### **Additional Notes**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
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